

U.S. Department of Commerce, Patent and Trademark Office				Atty Docket No.		Serial No.	
				M-15223 US		10/632,007	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)				Applicant			
				Yi Ding			
				Filing Date		Group	
				July 30, 2003		2822	

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U.S. Patent Documents							
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
<div style="border-left: 1px solid black; height: 100px; width: 100%;"></div>	AA	6,420,231	16 Jul. 2002	Harari et al.			
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						

Foreign Patent Documents							Translation	
		Document	Date	Country	Class	Subclass	Yes	No
<div style="border-left: 1px solid black; height: 100px; width: 100%;"></div>	AI							
	AJ							
	AK							
	AL							

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)		
	AM	United States Patent Application No. 10/798,475, entitled "Fabrication of Conductive Lines Interconnecting Conductive Gates in Nonvolatile Memories and Non-Volatile Memory Structures," Filed on March 10, 2004; Attorney Docket No. M-15296 US.
	AN	United States Patent Application No. 10/797,972, entitled "Fabrication of Conductive Lines Interconnecting First Conductive Gates in Nonvolatile Memories Having Second Conductive Gates Provided By Conductive Gates Lines, Wherein The Adjacent Conductive Gate Lines For The Adjacent Columns Are Spaced From Each Other, And Non-Volatile Memory Structures," Filed on March 10, 2004; Attorney Docket No. M-15297 US.
<div style="border-left: 1px solid black; height: 100px; width: 100%;"></div>	AO	
<div style="border-left: 1px solid black; height: 100px; width: 100%;"></div>	AP	

Examiner	Date Considered	10/1/04
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.

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